



DMP4013SPSQ

P-CHANNEL ENHANCEMENT MODE MOSFET PowerDI5060-8

# **Product Summary**

BV <sub>DSS</sub>	RDS(ON) Max	Ι <sub>D</sub> Tc = +25°C
40)/	15mΩ @ V <sub>GS</sub> = -10V	-61A
-40V	$23m\Omega @ V_{GS} = -4.5V$	-49A

### **Description and Applications**

This MOSFET is designed to meet the stringent requirements of automotive applications. It is qualified to AEC-Q101, supported by a PPAP and is ideal for use in:

- Reverse polarity protections
- BLDC motor controls
- Power-management functions

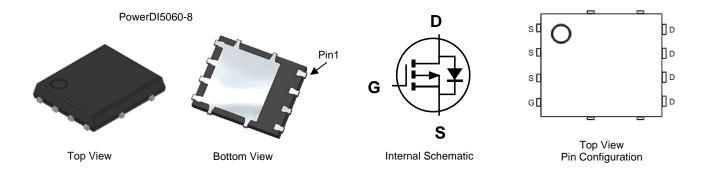
#### **Features and Benefits**

- 100% Unclamped Inductive Switch (UIS) Test in Production
- Low On-Resistance
- Fast Switching Speed
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- The DMP4013SPSQ is suitable for automotive applications requiring specific change control; this part is AEC-Q101 qualified, PPAP capable, and manufactured in IATF 16949 certified facilities.

https://www.diodes.com/quality/product-definitions/

#### Mechanical Data

- Package: PowerDI<sup>®</sup>5060-8
- Package Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections: See Diagram
- Terminals: Finish 100% Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 ()
- Weight: 0.097 grams (Approximate)



#### Ordering Information (Note 4)

Dort Number	Package	Packing		
Part Number	Package	Qty.	Carrier	
DMP4013SPSQ-13	PowerDI5060-8	2,500	Reel	

Notes:

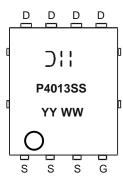
EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied.
See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.



### **Marking Information**



 $\supset$  : = Manufacturer's Marking P4013SS = Product Type Marking Code YYWW = Date Code Marking YY= Year (ex: 23 = 2023) WW = Week (01 to 53)

#### Maximum Ratings (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit		
Drain-Source Voltage	V <sub>DSS</sub>	-40	V		
Gate-Source Voltage	Vgss	±20	V		
Continuous Drain Current $V_{GS}$ = -10V (Note 7)	Steady State	T <sub>C</sub> = +25°C T <sub>C</sub> = +70°C	ID	-61 -49	А
Continuous Drain Current $V_{GS}$ = -10V (Note 6)	۱ <sub>D</sub>	-11 -9	А		
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%)		Ідм	-244	A	
Maximum Body Diode Continuous Current (Note 7)	ls	-61	А		
Pulsed Source Current (10µs Pulse, Duty Cycle = 1%)			lsм	-244	A
Avalanche Current (Note 8) L = 1mH			las	-16	A
Avalanche Energy (Note 8) L = 1mH			E <sub>AS</sub>	176	mJ

# Thermal Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Total Power Dissipation (Note 5)	T <sub>A</sub> = +25°C	PD	1.6	W
Thermal Resistance, Junction to Ambient (Note 5)	Steady State	Reja	96	°C/W
Total Power Dissipation (Note 6)	T <sub>A</sub> = +25°C	PD	3.4	W
Thermal Resistance, Junction to Ambient (Note 6)	Steady State	R <sub>0JA</sub>	44	°C/W
Thermal Resistance, Junction to Case (Note 7)		Rejc	1.5	°C/W
Operating and Storage Temperature Range		TJ, TSTG	-55 to +150	°C

Notes: 5. Device mounted on FR-4 PC board, with minimum recommended pad layout, single sided.

6. Device mounted on FR-4 substrate PC board, 2oz copper, with thermal bias to bottom layer 1 inch square copper plate.

7. Thermal resistance from junction to soldering point (on the exposed drain pad).

8.  $I_{AS}$  and  $E_{AS}$  ratings are based on low frequency and duty cycles to keep  $T_J = +25^{\circ}C$ .

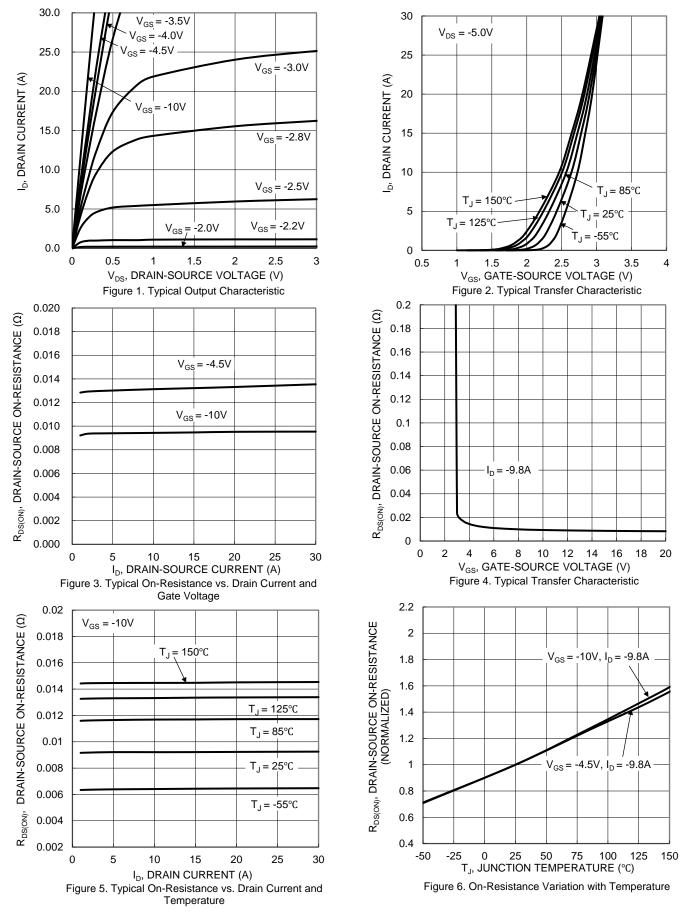


# Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 9)				1		1	
Drain-Source Breakdown Voltage	BVDSS	-40	_		V	$V_{GS} = 0V, I_D = -250\mu A$	
Zero Gate Voltage Drain Current	IDSS			-1	μA	$V_{DS} = -40V$ , $V_{GS} = 0V$	
Gate-Source Leakage	lgss	_		±100	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 9)							
Gate Threshold Voltage	VGS(TH)	-1		-3	V	$V_{DS} = V_{GS}$ , $I_D = -250 \mu A$	
Static Drain-Source On-Resistance	Descent	_	9.6	15		VGS = -10V, ID = -10A	
Static Drain-Source On-Resistance	RDS(ON)	_	13.4	23	mΩ	$V_{GS} = -4.5V, I_D = -8A$	
Diode Forward Voltage	Vsd	_	-0.7	-1.2	V	$V_{GS} = 0V$ , $I_{S} = -1A$	
DYNAMIC CHARACTERISTICS (Note 10)							
Input Capacitance	Ciss	_	4004				
Output Capacitance	Coss	_	309	_	pF	V <sub>DS</sub> = -20V, V <sub>GS</sub> = 0V f = 1MHz	
Reverse Transfer Capacitance	Crss	_	229	_			
Gate Resistance	Rg	_	3.5	_	Ω	$V_{DS} = 0V, V_{GS} = 0V, f = 1MHz$	
Total Gate Charge (V <sub>GS</sub> = -4.5V)	Qg	_	31	—			
Total Gate Charge (V <sub>GS</sub> = -10V)	Qg	_	67	_	nC	V <sub>DS</sub> = -20V, I <sub>D</sub> = -10A	
Gate-Source Charge	Qgs	_	13.2	_	no		
Gate-Drain Charge	Q <sub>gd</sub>	_	11	_			
Turn-On Delay Time	td(ON)	_	9.9	_			
Turn-On Rise Time	tR	_	32	_		$V_{GS} = -10V, V_{DD} = -20V,$ $R_G = 3\Omega, I_D = -10A$	
Turn-Off Delay Time	tD(OFF)		46	_	ns		
Turn-Off Fall Time	tF		53	_	]		
Reverse Recovery Time	t <sub>RR</sub>	_	19.5	_	ns	I <sub>F</sub> = -10A, di/dt = -100A/µs	
Reverse Recovery Charge	Qrr		11.6	_	nC	I <sub>F</sub> = -10A, di/dt = -100A/µs	

Notes:9. Short duration pulse test used to minimize self-heating effect.10. Guaranteed by design. Not subject to product testing.





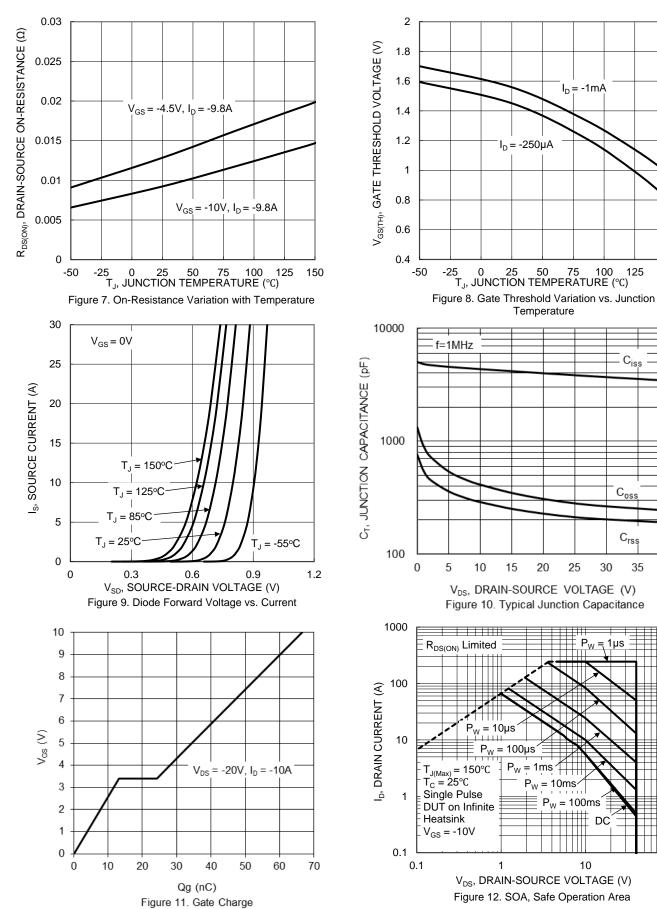
DMP4013SPSQ Document number: DS41825 Rev.4 - 2



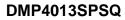
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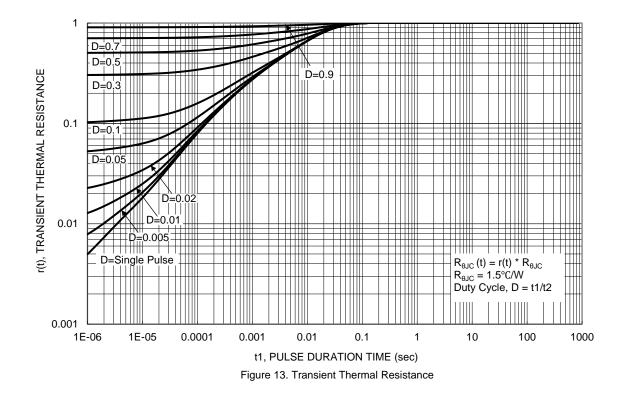
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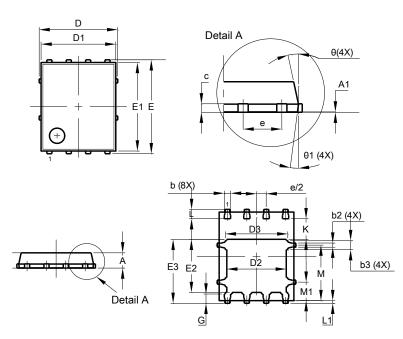






### **Package Outline Dimensions**

Please see http://www.diodes.com/package-outlines.html for the latest version.

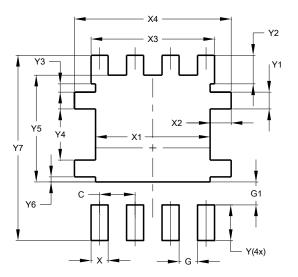


PowerDI5060-8						
Dim	Dim Min Max Typ					
A	0.90	1.10	1.00			
A1	0.00	0.05	1.00			
b						
	0.33	0.51	0.41			
b2	0.200	0.350	0.273			
b3	0.40	0.80	0.60			
С	0.230	0.330	0.277			
D		5.15 BSC	;			
D1	4.70	5.10	4.90			
D2	3.70	4.10 3.9				
D3	3.90 4.30 4.10					
ш	6.15 BSC					
E1	5.60	6.00	5.80			
E2	3.28	3.68	3.48			
E3	3.99	4.39	4.19			
е	1.27 BSC					
G	0.51	0.71	0.61			
K	0.51	_	_			
L	0.51	0.71	0.61			
L1	0.100	0.200	0.175			
М	3.235	4.035	3.635			
M1	1.00	1.40	1.21			
Θ	10°	12°	11°			
Θ1	6°	8°	7°			
Al	All Dimensions in mm					

# Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

#### PowerDI5060-8



Dimensions	Value (in mm)			
С	1.270			
G	0.660			
G1	0.820			
Х	0.610			
X1	4.100			
X2	0.755			
X3	4.420			
X4	5.610			
Y	1.270			
Y1	0.600			
Y2	1.020			
Y3	0.295			
Y4	1.825			
Y5	3.810			
Y6	0.180			
¥7	6.610			

#### PowerDI5060-8



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